

Photo DMOS-FET Relay

Description

The **LT425** is a 1-Form A solid state relay in an 4 pin DIP package that employs optically coupled MOSFET technology to provide 3750V/5000V of input to output isolation. The optically coupled input is controlled by a highly efficient GaAlAs infrared LED and MOS FETs on the output side.

Features

- Low driver power requirements (TTL/CMOS Compatible)
- No moving parts
- High reliability
- Arc-Free with no snubbing circuits
- 3750 / 5000Vrms Input/Output isolation

Applications

- Telecommunications (PC, Electronic notepad)
- Measuring and Testing equipment
- Industrial control
- Security equipments
- High speed inspection machine

Outline Dimensions

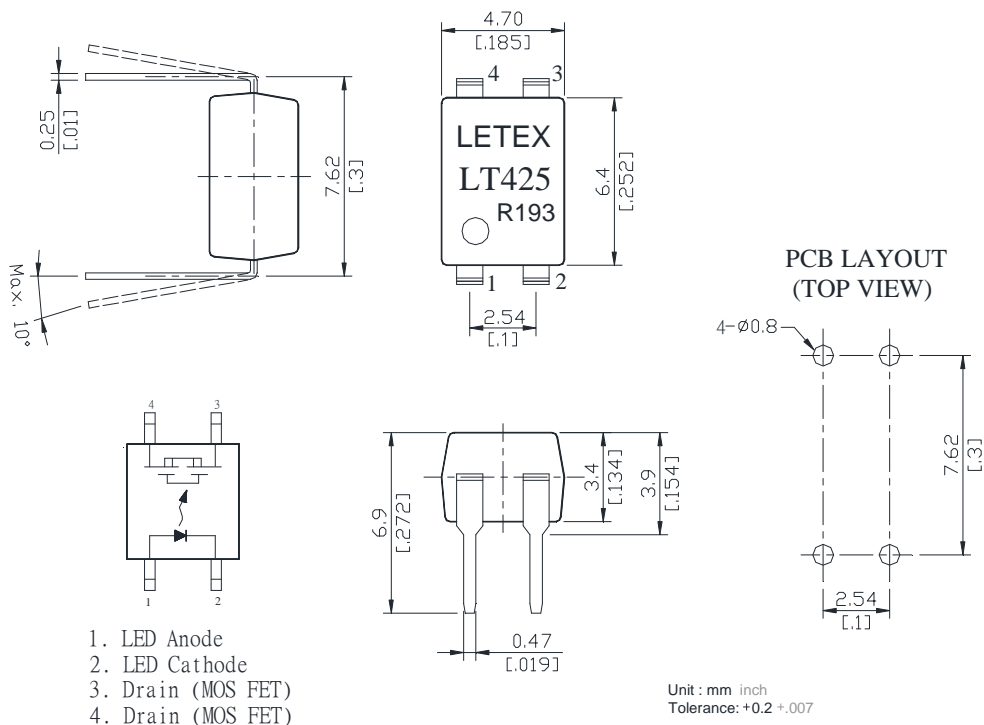


Photo DMOS-FET Relay Specifications

Part Name: LT425

(Load voltage: 100V / Load current: 1.25A)

Absolute Maximum Ratings (Ambient Temperature: 25°C)

Item	Symbol	Value	Units	Note	
Input	Continuous LED Current	I _F	50	mA	
	Peak LED Current	I _{FP}	1000	mA	f=100Hz, duty=1%
	LED Reverse Voltage	V _R	5	V	
	Input Power Dissipation	P _{In}	75	mW	
Output	Load Voltage	V _L	100	V(AC peak or DC)	
	Load Current	I _L	1.25	A	
	Peak Load Current	I _{Peak}	6.0	A	100ms(1 pulse)
	Output Power Dissipation	P _{out}	350	mW	
Total Power Dissipation	P _T	400	mW		
I/O Breakdown Voltage	V _{I/O}	3750	V _{rms}	RH=60%, 1min	
I/O Breakdown Voltage(Suffix-V)	V _{I/O}	5000	V _{rms}	RH=60%, 1min	
Operating Temperature	T _{opr}	-40 to +85	°C		
Storage Temperature	T _{stg}	-40 to +100	°C		
Pin Soldering Temperature	T _{sol}	260	°C	10 sec max.	

Electrical Specifications (Ambient Temperature: 25°C)

Item	Symbol	MIN.	TYP.	MAX.	Units	Conditions
Input	LED Forward Voltage	V _F	1.2	1.5	V	I _F =10mA
	Operation LED Current	I _{F on}	1.0	3.0	mA	
	Recovery LED Current	I _{F off}	0.35	0.8	mA	
	Recovery LED Voltage	V _{F off}	0.7		V	
Output	On-Resistance	R _{on}	0.15	0.25	Ω	I _F =10mA, I _L =100mA, Time to flow is within 1 sec.
	Off-State Leakage Current	I _{Leak}		1.0	uA	V _L =Rating
	Output Capacitance	C _{out}		115	pF	V _L =0, f=1MHz
Transmission	Turn-On Time	T _{on}	1.5	3.5	ms	I _F =10mA, I _L =100mA,
	Turn-Off Time	T _{off}	0.035	0.3	ms	
Coupled	I/O Isolation Resistance	R _{I/O}	10 ¹⁰		Ω	DC500V
	I/O Capacitance	C _{I/O}	0.8	1.5	pF	f=1MHz

Reference Data

